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Supplemental Information

**Molybdenum Nitride Nanocrystals Anchored on
Phosphorus-Incorporated Carbon Fabric as a
Negative Electrode for High-Performance
Asymmetric Pseudocapacitor**

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Transparent Methods

Chemicals

The phosphomolybdic acid ($\text{H}_3\text{PMo}_{12}\text{O}_{40}\cdot 3\text{H}_2\text{O}$ Kegging type, PMo_{12}), hydrochloric acid (HCl), acetone ($\text{C}_3\text{H}_6\text{O}$), ethanol ($\text{C}_2\text{H}_6\text{O}$), hydrogen peroxide (H_2O_2) and Ruthenium (III) chloride ($\text{RuCl}_3\cdot x\text{H}_2\text{O}$), polyvinyl alcohol (PVA) was purchased from sigma Aldrich. The carbon fabric (WOS1002 Carbon Cloth Substrate with thickness 360 μm) was purchased from FC Internationals, South Korea. All reagents were used as received without further purification. All the precursor solutions were prepared by using the MilliQ water.

Design and synthesis of MoN@P-CF

Prior to the deposition, the commercial CF was cleaned with acetone, ethanol and deionized (DI) water using ultrasonic bath (20 min each) and dried in the oven at temperature 80 °C for 24 hr. Initially, well-cleaned CF was immersed in 10 mM phosphomolybdic acid ($\text{H}_3\text{PMo}_{12}\text{O}_{40}\cdot 3\text{H}_2\text{O}$, PMo_{12}) solution and sonicated for 30 min. Later, the precursor solution with CF was transferred to Teflon-linked stainless steel autoclave and treated at 120°C for 12 h to achieve PMo_{12} nanoclusters decorated CF. The PMo_{12} @CF sample was cleaned with MilliQ water and dried in vacuum oven at 70 °C for 12 hr. Finally, the as-prepared PMo_{12} @CF were annealed in tube furnace under ammonia gas flow with a temperature rate of 3 °C/min at three different temperatures 700 °C, 800 °C and 900 °C for 5 hours. The prepared samples were denoted as MoN@P-CF-700, MoN@P-CF-800 and MoN@P-CF-900. All the samples were preserved in vacuum sealed desiccator to avoid the oxidation.

Synthesis of RuO₂ on carbon fabric (CF)

This is the first report on the synthesis of RuO₂ on CF by Layer-by-Layer (LBL) deposition method. This is very simple, cost-effective and large scale deposition method. For the deposition of RuO₂ on CF, 10 mM RuCl₃ was used as the cationic precursor while MilliQ water with 3-4 drops of H₂O₂ maintained at 80 °C was utilized as anionic precursor solution. Pre-cleaned CF substrate was immersed in a cationic solution (RuCl₃) for 20 sec where the ruthenium species adsorbed on to the CF surface. The CF-substrate was rinsed in MilliQ water for 5 sec to remove loosely bound Ru species. Later, Ru-species@CF substrate was immersed in anionic solution (kept at 80 °C) for 20 sec to form a layer of hydrous ruthenium oxide material. Finally, the CF-substrate was again rinsed for 5 sec to remove excess or unreacted species. We have performed 120 deposition cycles to get a terminal thickness where the mass loading was determined to be 0.9 mg/cm². After complete reaction cycles, the RuO₂@CF samples were cleaned with water and dried in vacuum oven for 12 hr at 70 °C.

Materials characterizations

All the samples were characterized by using different characterizations techniques. The structural analysis was performed by Powder X-ray diffraction patterns using X-ray Powder Diffractometer (Rigaku MiniFlex600) (Cu K α radiation and PIXel detector). The compositional information as collected using Raman spectra, which was recorded using Raman Spectrometer (Horiba Scientific). The oxidation states and surface composition various elements in the sample was measured using X-ray photoelectron spectroscopy XPS (ESCALAB-MKII). The surface morphological analysis were performed using series of characterization techniques such as field-emission scanning electron microscopy, FE-SEM (FEI Quanta 450 FEG Environmental SEM) and transmission electron microscopy, TEM (FEI Titan Themis 80-200). The energy-dispersive X-ray spectroscopy (EDS) analyzer attached to the FE-SEM was used to investigate the elemental composition.

Assembly of solid-state all pseudo-capacitive MoN@P-CF//RuO₂@CF asymmetric cell

Prior to assemble a full cell, MoN@P-CF and RuO₂@CF electrodes were tested in 1 M H₂SO₄ using 3-electrode configuration. In order to approach the highest cell voltage, the charges stored in positive and negative electrodes must be balanced by adjusting the mass loading of each of the active electrode materials. The capacitance of the MoN@P-CF (negative electrode) and RuO₂@CF (positive electrode) were balanced to satisfy $Q_+ = Q_-$.

$$\frac{m_{MoN}}{m_{RuO_2}} = \frac{C_{RuO_2} \times E_{RuO_2}}{C_{MoN} \times E_{MoN}} = \frac{2}{1} \quad (1)$$

The mass ratio of MoN@P-CF:RuO₂@CF was maintained to ~ 1:2. Thus, the total mass loading of active material in both electrodes was 3.4 mg/cm². The W₂N@P-CF//PPy@CF asymmetric device was assembled in coin cell design with 1 M H₂SO₄ electrolyte and a glass fiber separator.

The asymmetric cell was fabricated using MoN@P-CF as a negative electrode, RuO₂@CF as a positive electrode with PVA-H₂SO₄ gel as electrolyte and separator. PVA-H₂SO₄ gel-electrolyte was prepared by dissolving 3 g of PVA in 30 mL of deionized water at 70 °C under vigorous stirring for 60 min. After cooling down, 3 g of H₂SO₄ was added in the PVA solution and vigorously stirred for next 30 min to form a polymer gel-electrolyte. Now, both MoN@P-CF and RuO₂@CF electrodes were soaked in gel-electrolyte for 2 min and then dried at room temperature for 12 h to form a thin layer of the gel electrolyte on both the electrode. Finally, both the electrodes were pressed on each other to form flexible all pseudocapacitive solid-state MoN@P-CF and RuO₂@CF asymmetric cell.

Electrochemical Measurements

The electrochemical performances of individual electrodes and final asymmetric cells such as cyclic voltammetry (CV), galvanostatic charge/discharge (GCD) and electrochemical impedance (EIS) were conducted using a CHI760D electrochemical workstation. For three-electrode measurements, MoN@P-CF and RuO₂@CF electrodes were used as the working electrodes with platinum wire and Ag/AgCl as the counter and reference electrodes, respectively.

Calculations: Gravimetric (F/g) and areal specific capacitance (mF/cm²) of electrode materials was calculated from the CD curves by integrating the discharge portion using the following equation:

$$C_s = \frac{I \times \Delta t}{m \times V} \text{ OR } C_A = \frac{I \times \Delta t}{A \times V} \quad (2)$$

where I is the current (mA), V is the potential window (V) and m is the mass of the active material (mg).

Two-electrode configuration (cell measurements)

The areal (C_A) and volumetric (C_V) capacitance were estimated from the slope of the discharge curve using the following equations:

$$C_A = \frac{I \int V dt}{Area \times V^2} \text{ OR } C_V = \frac{I \int V dt}{Volume \times V^2} \quad (3)$$

Where C_A and C_V are areal and volumetric capacitances, respectively. I is the applied current, Δt is the discharging time, V (V) is the voltage window, Volume (cm³) of the whole device (The area and thickness of our asymmetric cells is about 0.785 cm² (Area, $A = \pi r^2$, $3.14 \times (0.5)^2$) and 0.088 cm. Hence, the whole volume of device is about 0.069 cm³, ΔV (V) is the voltage window. It is worth mentioning that the volumetric capacitances were calculated taking into account the volume of the device stack. This includes the active material, the flexible substrate and the separator with electrolyte.

Volumetric energy (E , Wh/cm³) and power density (P , W/cm³) of the devices were obtained from the following equations:

$$E = \frac{1}{2 \times 3600} C_V \Delta V^2 \quad (4)$$

$$P = \frac{3600 \times E}{\Delta t} \quad (5)$$

where E (Wh/cm³) is the energy density, C_V is the volumetric capacitance obtained from Equation (4) and ΔV (V) is the voltage window, P (W/cm³) is the power density.

Electrochemical Impedance Calculations:

Furthermore, the capacitive behavior of device can also be evaluated from EIS technique by calculating the real and imaginary capacitance at a corresponding frequency using following equations:

$$C(\omega) = C'(\omega) - jC''(\omega) \quad (6)$$

$$\text{Where, } C'(\omega) = \frac{Z''(\omega)}{\omega |Z(\omega)|^2} \quad (7)$$

$$C''(\omega) = \frac{Z'(\omega)}{\omega |Z(\omega)|^2} \quad (8)$$

where 'Z' the complex impedance represented as $Z(\omega) = Z'(\omega) + jZ''(\omega)$ and $\omega = 2\pi f$ where f is the frequency. $C'(\omega)$ is the real accessible capacitance of the electrode while $C''(\omega)$ is the energy loss due to the irreversible processes of the electrodes, Z' and Z'' are the real and imaginary parts of the Nyquist plot, respectively.

Density Functional Theory (DFT) computational details and models

All Density functional theory (DFT) simulations were carried out using the Vienna ab initio simulation package (VASP) (Kresse et al. 1993; Kresse et al. 1994) with the projector augmented wave pseudopotentials (PAW) (Blochl, 1994) and the periodic boundary conditions. The Brillouin zone was sampled using $3 \times 3 \times 1$ a Monkhorst-pack (Monkhorst and Pack, 1976) gamma centered mesh, and Gaussian smearing of 0.015 eV was used for the occupations of the electronic levels. Perdew-Burke-Ernzerhof (PBE) (Perdew et al. 1996; Perdew et al. 1997) functional within the generalized gradient approximation (GGA), was used to describe the electron interaction energy of exchange correlation. The electronic energies were converged within the limit of 10^{-7} eV and a cutoff of 600 eV was used. All geometries were optimized using 0.01 eV/Å force criteria. All the calculations were spin polarized. H_3O^+ molecules were used to carry out all the proton adsorption calculations for CF, P-CF, MoN and their interfaces. The adsorption energy of proton within the supercells was calculated as follows:

$$E_{S@H_3O} = E_{S@H_3O} - [E_S + E_{H_3O^+}]$$

Where $E_{S@H_3O}$ is the total energy of the substrate (CF, P-CF, MoN@CF, MoN@P-CF) with the adsorbed H_3O^+ , E_S is the total energy of a clean slab, and $E_{H_3O^+}$ is the energy of the hydronium cation. Through all the calculations, DFT+D3 approach developed by Grimme, was used for the long-range dispersion correction (Grimme et al. 2010).

For graphene fiber (CF) model, we have adopted 7×7 supercell (98 C atoms) and doped it with one and two phosphorus atoms which are corresponding to 1.0 at% and 2.0 at% of P:C, the latter is the

experimental atomic ratio (2.1 at%). We decide to use very large graphene layer and large vacuum distance of 20 Å in order to minimize the charge-image interactions. We have adopted P-sp³ type in our calculation because it reported as the most stable configuration of P-doped graphene system (P-CF) (Yang et al. 2017).

For MoN nanoparticles, we have modeled it using a 2 x 2 x 1 (100) slab of the hexagonal MoN (128 atoms) (Bull et al. 2004) and a thickness of 8 layer. Four of them were frozen and the upper four layers were relaxed. GGA+U formalism was used to describe the strong on-site coulomb interactions; we have adopted Dudraev et. al approach (Dudraev et al. 1998) which involves one parameter called the effective U (U-J, where U is the on-site coulomb repulsion and J is the on-site Hund exchange coupling. The U parameter was set to 3.0 eV in all our simulations involved MoN and the anti-ferromagnetic state used to describe the magnetism of the slab. The interfaces of MoN@CF and MoN@P-CF were generated using 6 x 6 x 1 of graphene sheet (CF, 72 atoms) and the above mentioned MoN slab. Here, we kept the doping ratio 1.4 at % for P-CF (which very near from of the experimental ratio 2.1 at%) to minimize the computational cost. The binding charge density was calculated using VESTA (Momma et al. 2011). Atom In Molecules (AIM) approach was used for the atomic charge analysis using bader code developed by henkelman group (Yu et al. 2011).

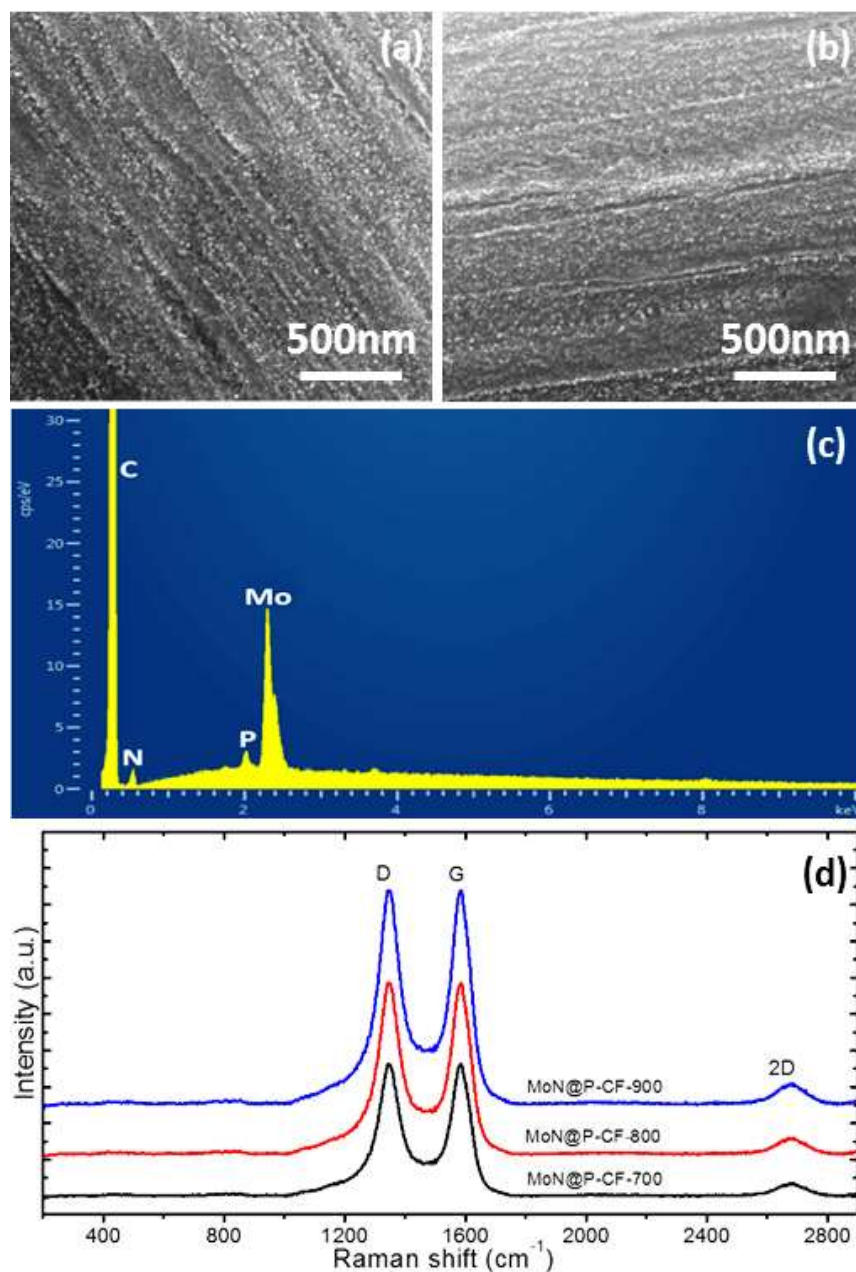


Figure S1 Characterizations of MoN@P-CF samples, Related to Figure 2. (a, b) SEM images of MoN@P-CF-700 and MoN@P-CF-800 samples, respectively. (c) EDAX pattern of MoN@P-CF-900 electrode, confirming the presence of Mo, N, C and P. (d) and (b) Raman spectra for MoN@P-CF samples prepared at different nitridation temperatures.

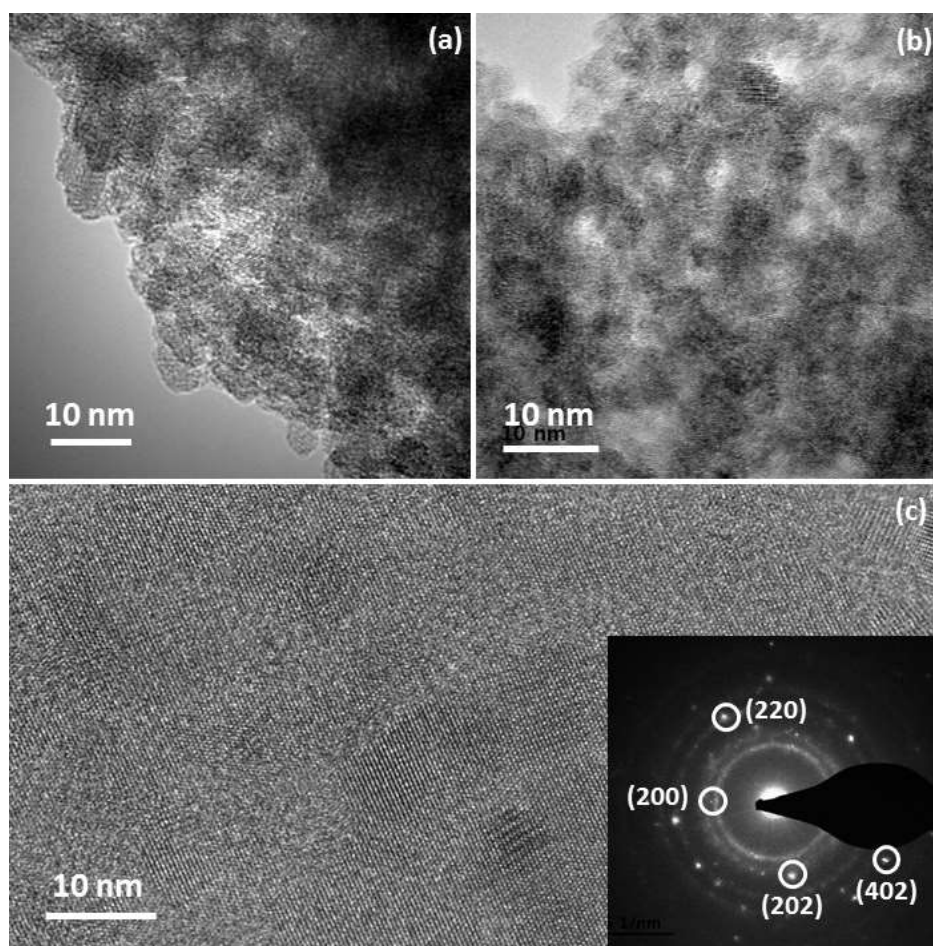


Figure S2 Characterizations of MoN@P-CF samples, Related to Figure 2. (a, b) TEM images for the MoN@P-CF sample prepared at 900 C, implying the formation of ultra-small MoN nanoparticle with the size less than 10 nm. (c) High magnified TEM image reveals that the MoN nanoparticles are crystalline in nature where distinct fringes can be clearly observed.

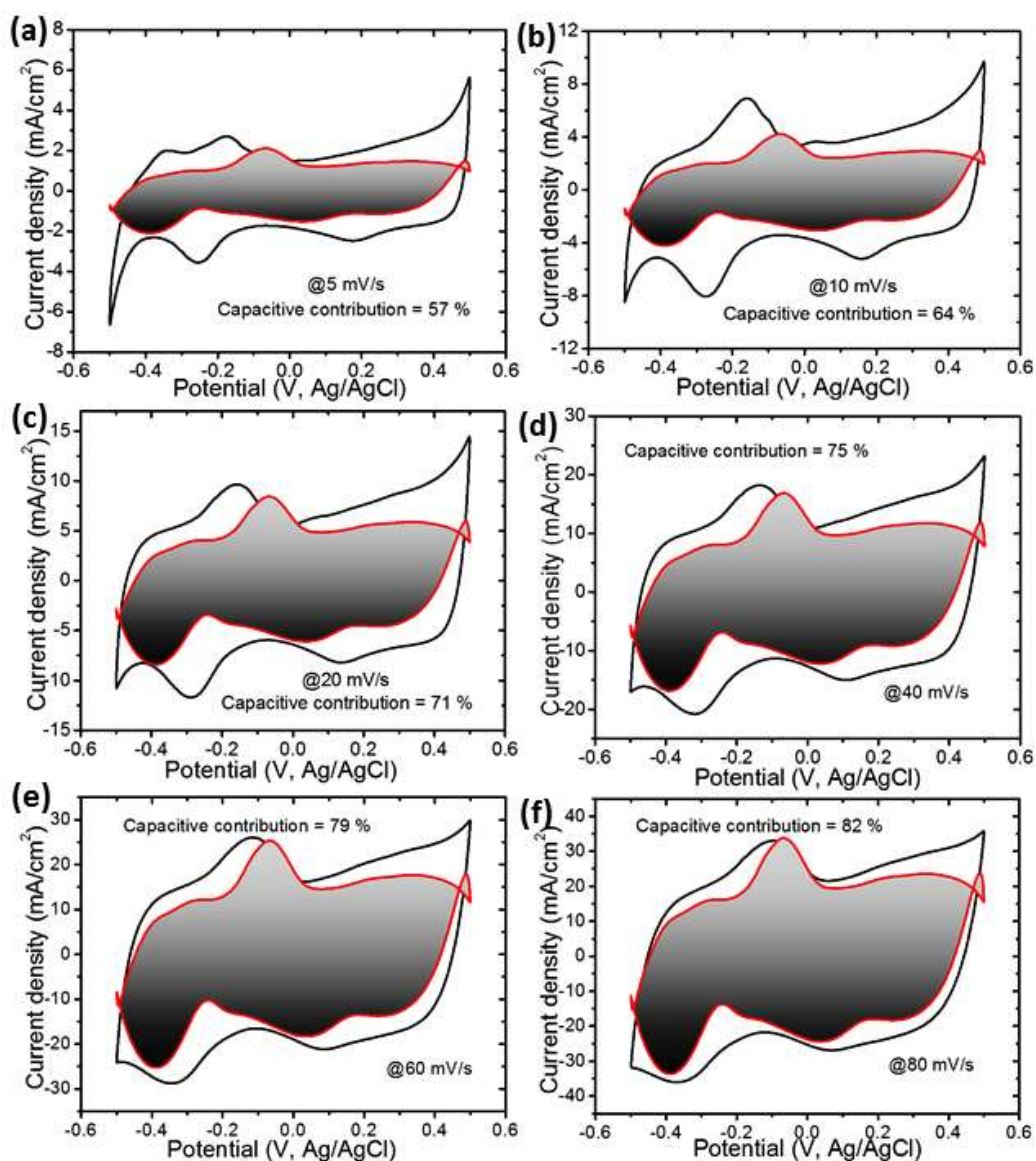


Figure S3 Electrochemical characterization of MoN@P-CF samples, Related to Figure 3. Cyclic voltammetry curves for MoN@P-CF-900 electrode at different scan rates from 10 to 100 mV/s. The capacitive contribution to the total current is shown by the shaded region.

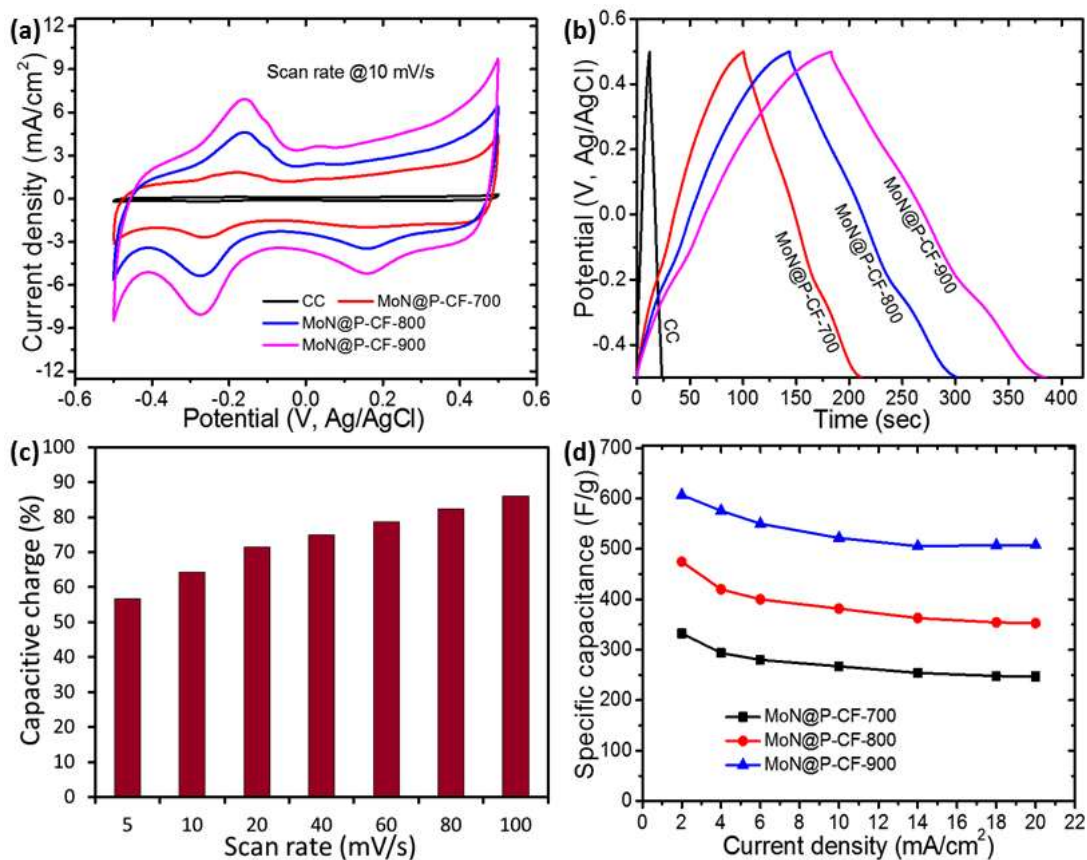


Figure S4 Electrochemical characterization of MoN@P-CF samples, Related to Figure 3. (a, b) Cyclic voltammety and Galvanostatic CD curves recorded for MoN@P-CF samples prepared at different nitridation temperatures. (c) Variation of capacitive contribution with scan rate. (d) Variation of specific capacitance with current densities for different MoN@P-CF electrodes.

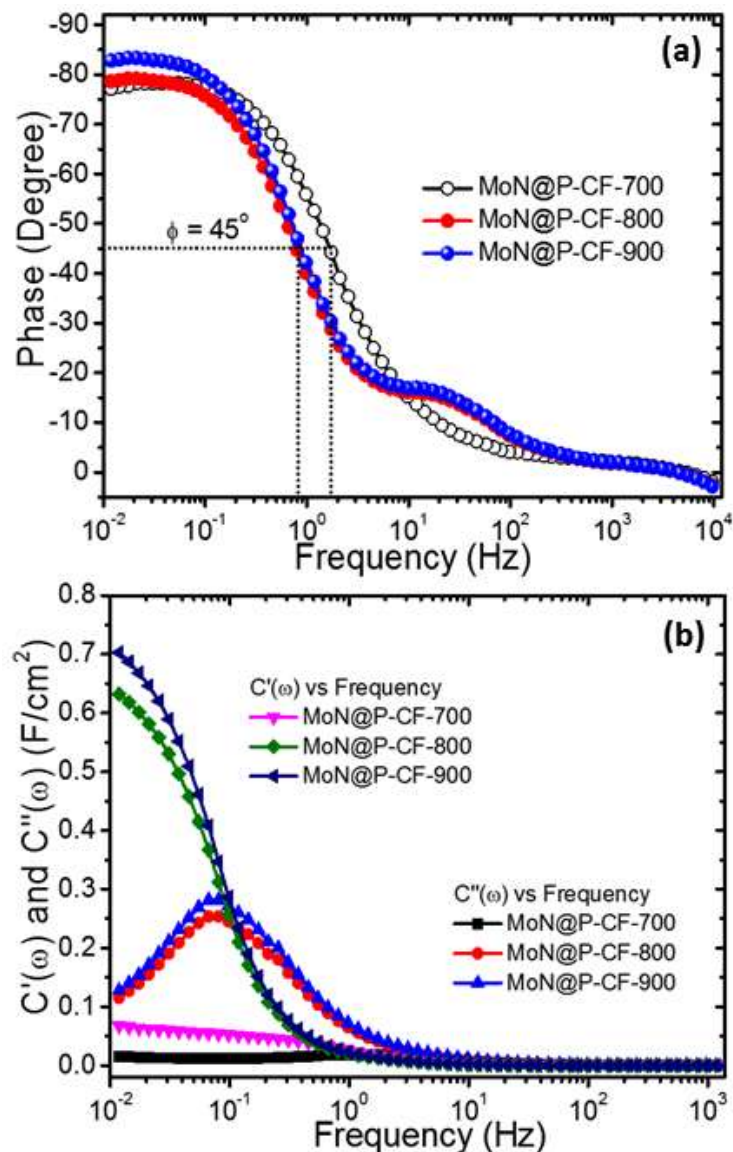


Figure S5 Electrochemical characterization of MoN@P-CF samples, Related to Figure 3. (a) Bode plots and (b) Real and imaginary capacitances with frequency for the MoN@P-CF samples prepared at different nitridation temperatures. The plot shows common relaxation-type dispersions where the real capacitance C' reduces with frequency while C'' shows maxima.

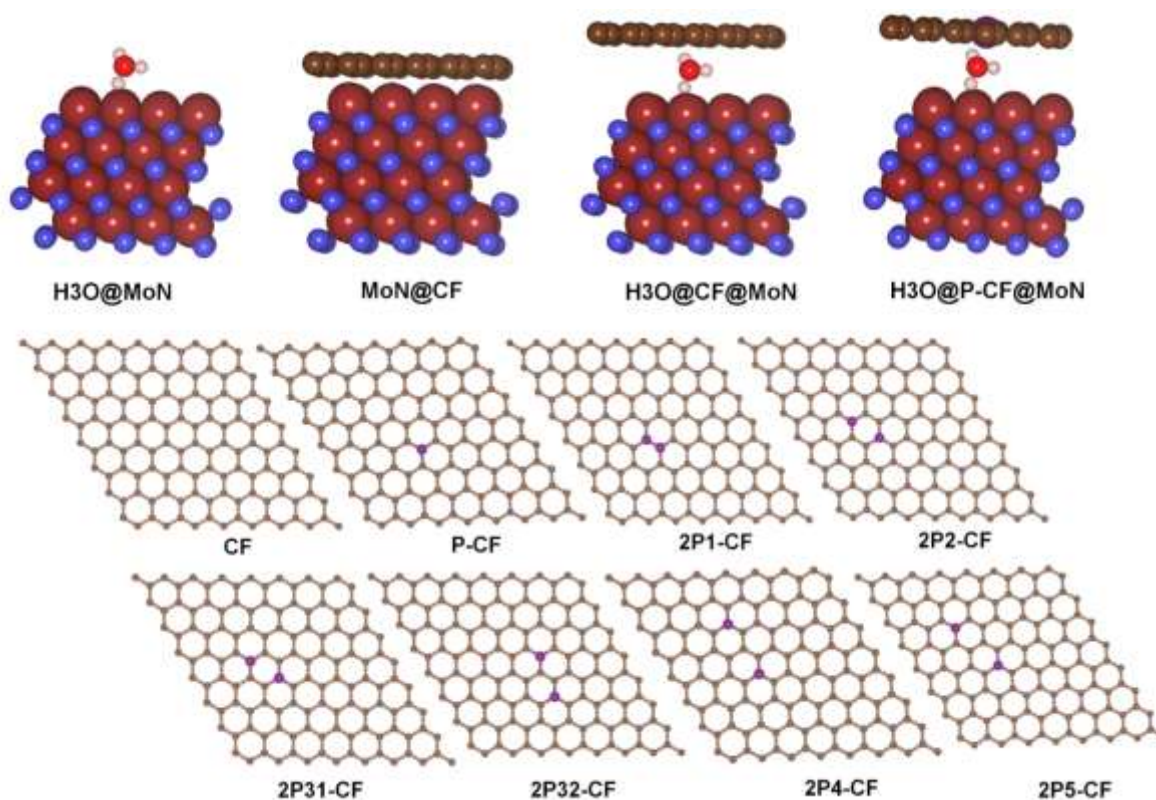


Figure S6 Initial Models of our DFT simulations of H₃O⁺ adsorption on CF, P-CF, MoN, MoN@CF, and MoN@P-CF systems, Related to Figure 4. MoN, MoN@CF, MoN@P-CF, and H₃O⁺ are represented by balls. Color code: MoN:plum, N:blue, C:brown, O:red, P:pink, and H:white. Isolated CF and P-CF models are shown in the lower panel and represented in balls and sticks. Different relative positions of the two phosphorus atoms (pink color spheres) are noted by Arabic numbers such as: P-CF, graphene sheet doped with one phosphorus, 2P1-CF is graphene doped by two phosphorus separated by one bond, 2P31-CF is graphene doped by two phosphorus and separated by two bonds and first configuration. The second Arabic letter after the phosphorus atom refers to the configuration numbers.

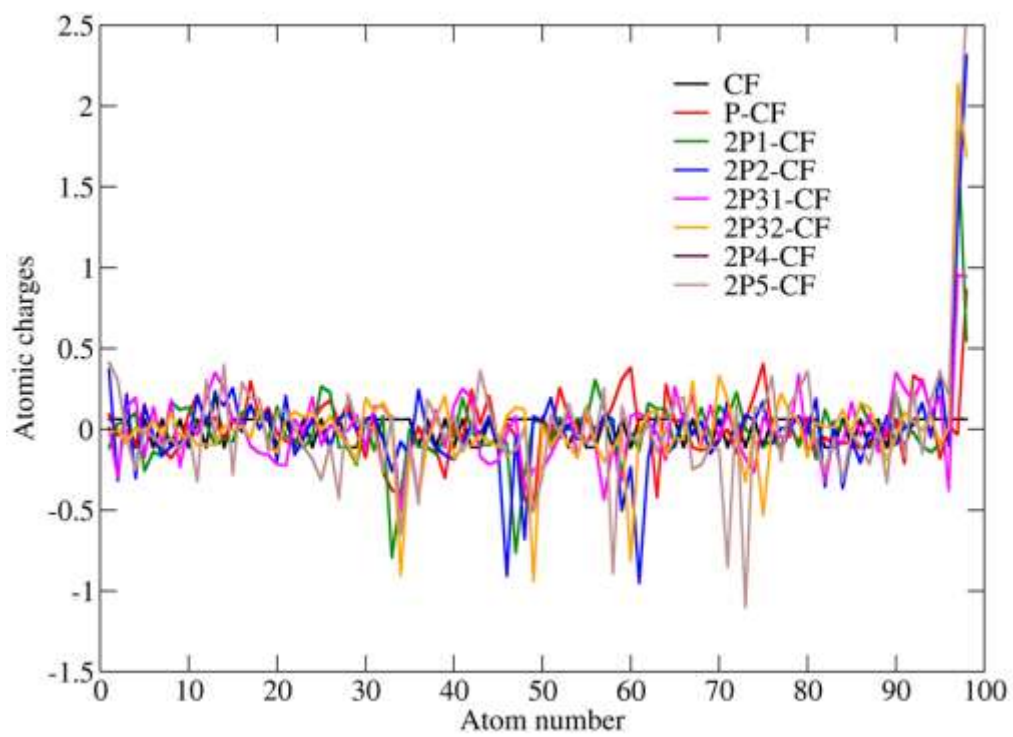


Figure S7 AIM atomic charges are shown for all CF and P-CF models, Related to Figure 4

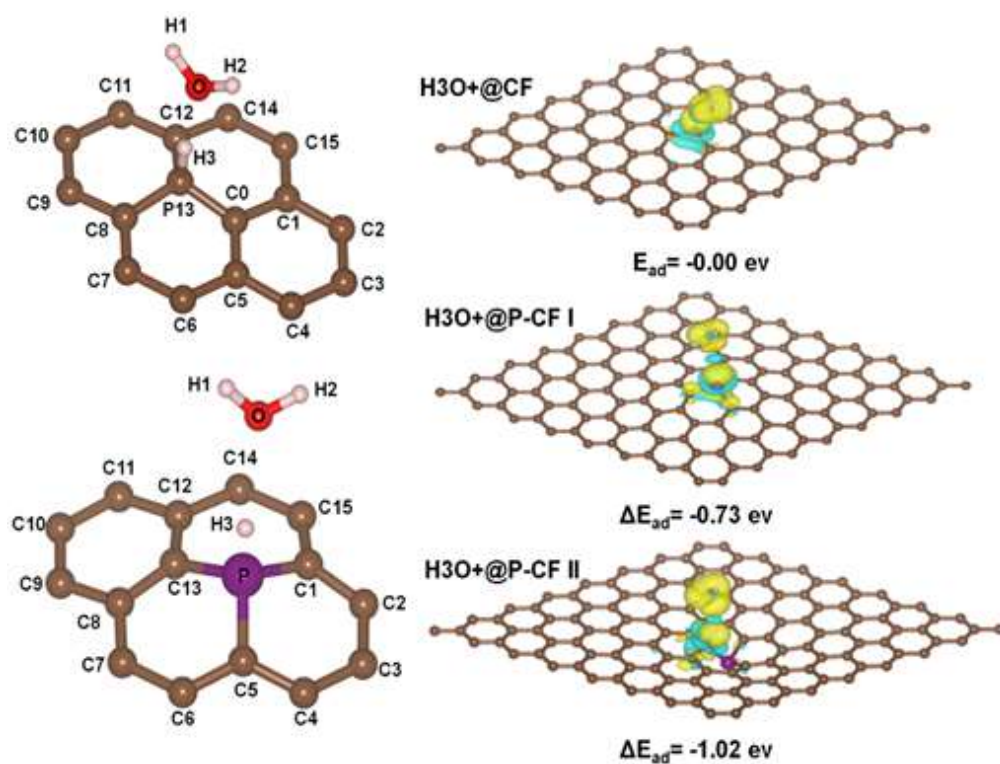


Figure S8 Binding charge densities of H_3O^+ on the pristine CF and P-CF in two different mode of adsorption, Related to Figure 4. The isosurfaces is represented in resolution of 0.0025 electron/bohr³. Yellow is rich and blue is depletion of electron density. Left panel is showing the important carbon atoms surrounding the H_3O^+ adsorption site in case of CF and P-CF I.

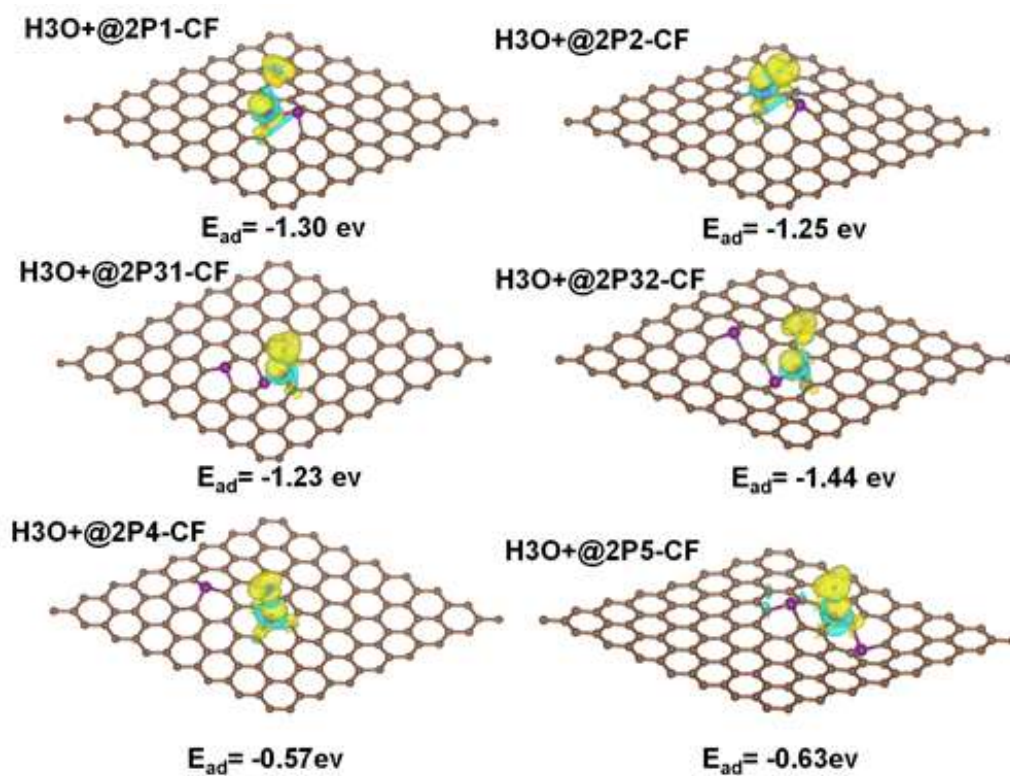


Figure S9: Binding charge densities of H_3O^+ on P-CF models following the same nomenclature reported in Figure S6, Related to Figure 4. The isosurfaces is represented in resolution of 0.015 electron/bohr³. Yellow is rich and blue is depletion of electron density.

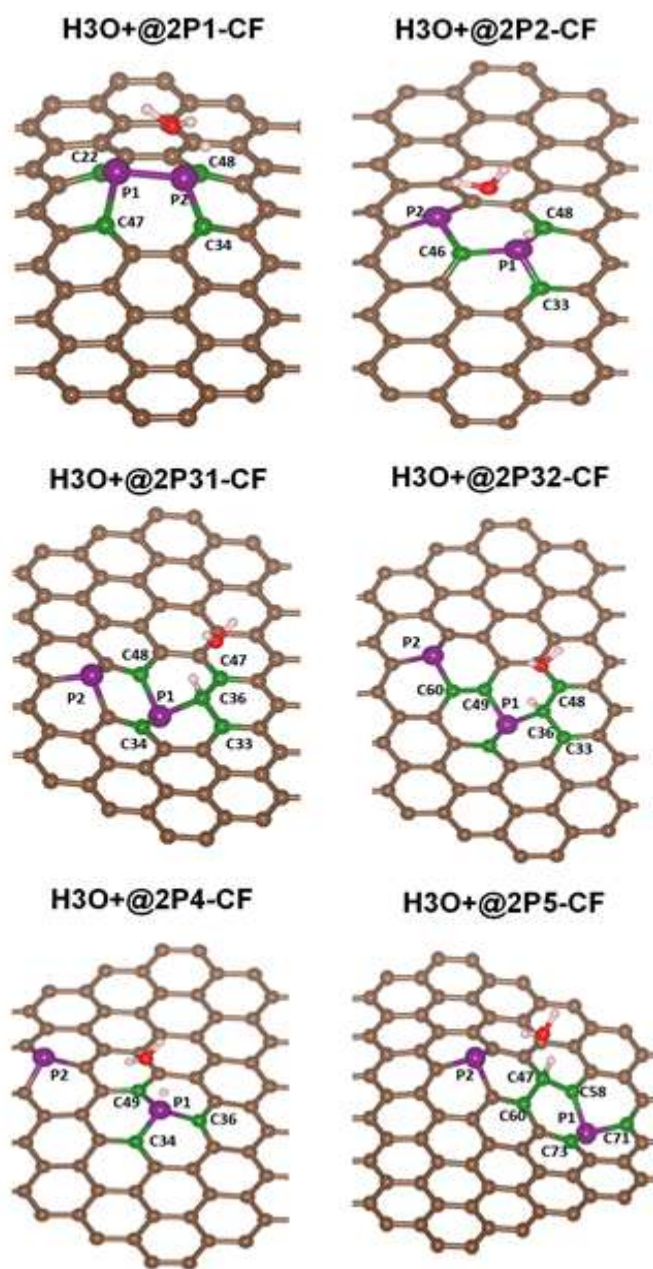


Figure S10 H3O⁺ binding sites of the P-CF considered systems depicted in Figure S9, Related to **Figure 4**. The important carbon atoms are colored in green the remaining is following the color code in Figure S6 and S9. The corresponding atomic charges are reported in Table S2.

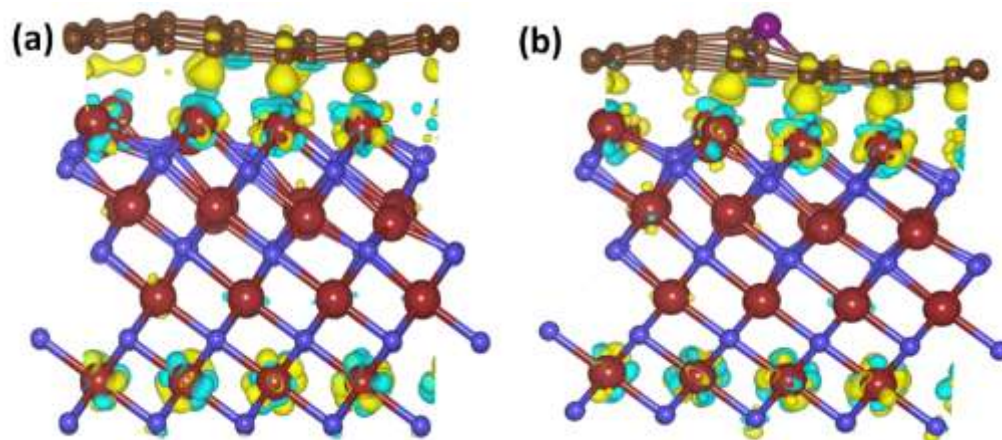
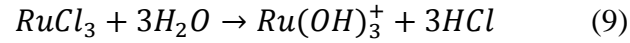


Figure S11 Charge density difference between the nano-composite MoN@CF, and MoN@P-CF, and their fragments (isolated slab, CF, and P-CF sheets), Related to Figure 4. The isosurfaces is represented in resolution of 0.015 electron/bohr³. Yellow is rich and blue is depletion of electron density. Color code is the same as in Figure S6.

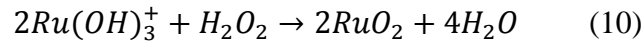
RuO₂@CF: Film formation mechanism, Related to Figure 5.

The deposition of RuO₂ on the surface of carbon fabric (CF) was carried out using Layer-by-Layer method (LBL) by immersing CF in separately placed cationic and anionic precursors with rinsing between every immersion. The growth kinetics of the deposition process is based on ion-by-ion deposition at nucleation sites on the immersed surfaces.

In present investigation, RuO₂ were grown on the surface of CF through a controlled heterogeneous precipitation of RuCl₃. The proposed reaction mechanism is as follows: thin layer of Ru-species are adsorbed on the CF-substrate by immersion of the CF into the cationic precursor solution kept at room temperature (10 mM RuCl₃).



With further reaction is followed by the immersion of the wet substrate in H₂O₂ anionic solution, where the chemical reaction between oxygen species and pre-adsorbed Ru-species leads to the formation of thin layer of RuO₂ on the surface of CF.



This completes one cycle of deposition of RuO₂ at CF. We have performed different number of deposition cycles to obtain desired mass loadings.

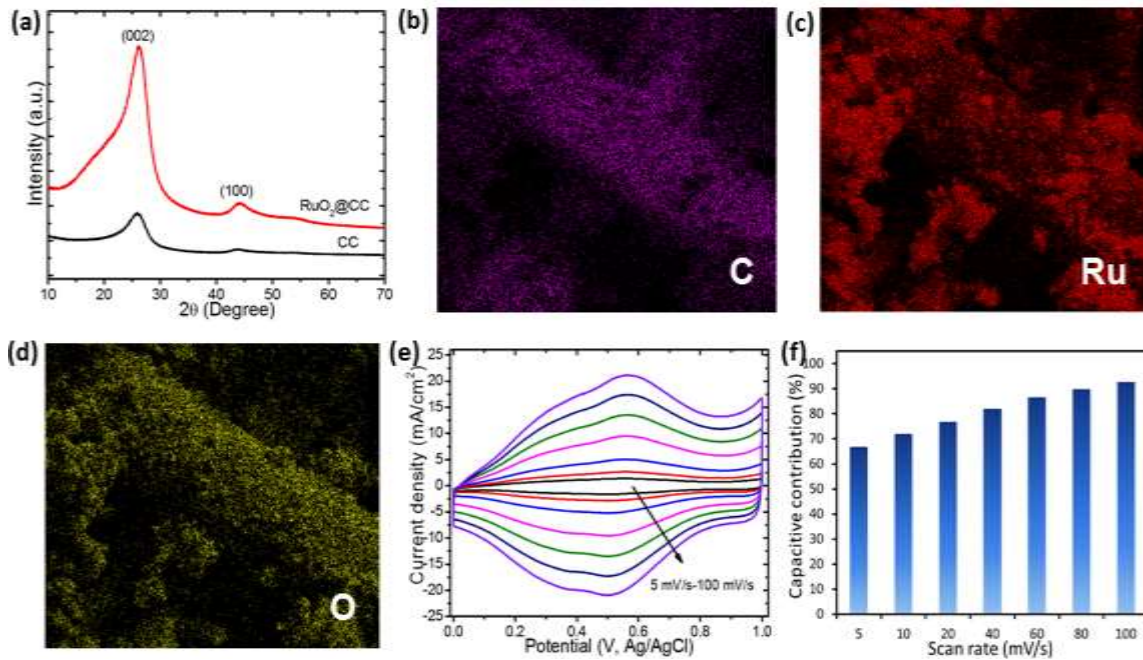


Figure S12 Characterizations of RuO₂@CF, Related to Figure 5. (a) XRD patterns of bare and RuO₂ coated carbon fabric electrodes. (b-d) EDS mapping images, displaying homogeneous coating of C, Ru and O, respectively. (e) CV curves measured at different scan rates in 1M H₂SO₄ electrolyte. (f) Plot of capacitive contribution as a function of scan rates.

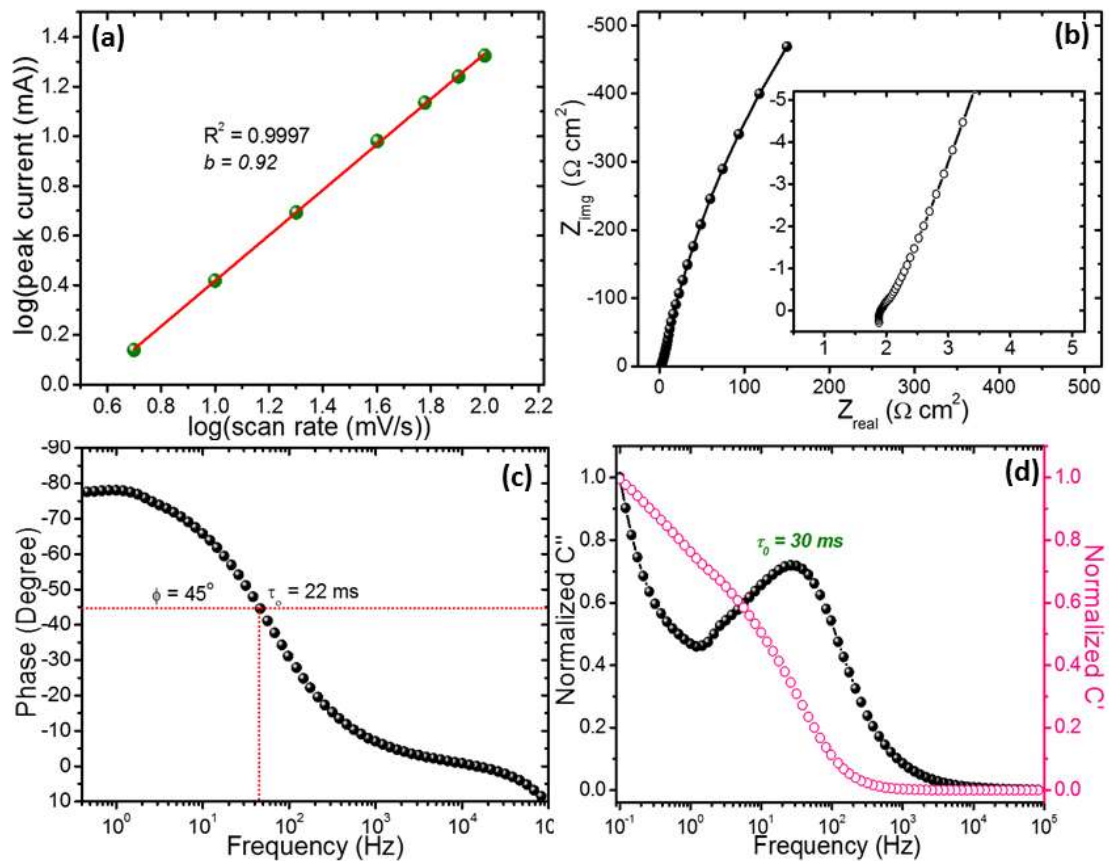


Figure S13 Electrochemical characterizations of RuO₂@CF, Related to Figure 5: (a) A plot of log (peak current, i) versus log(scan rate, mV/s), suggesting the major contribution to total current is from pseudocapacitive mechanism ($b=0.92$). (b) Nyquist plot recorded in the frequency range of 10 mHz to 100 kHz with amplitude of 5 mV. (c) Bode plots and (d) Real and imaginary capacitances with frequency, implying fast charge/discharge rates as relaxation time constant ($\tau_0 = 1/f_0$) was found to be 22-30 ms.

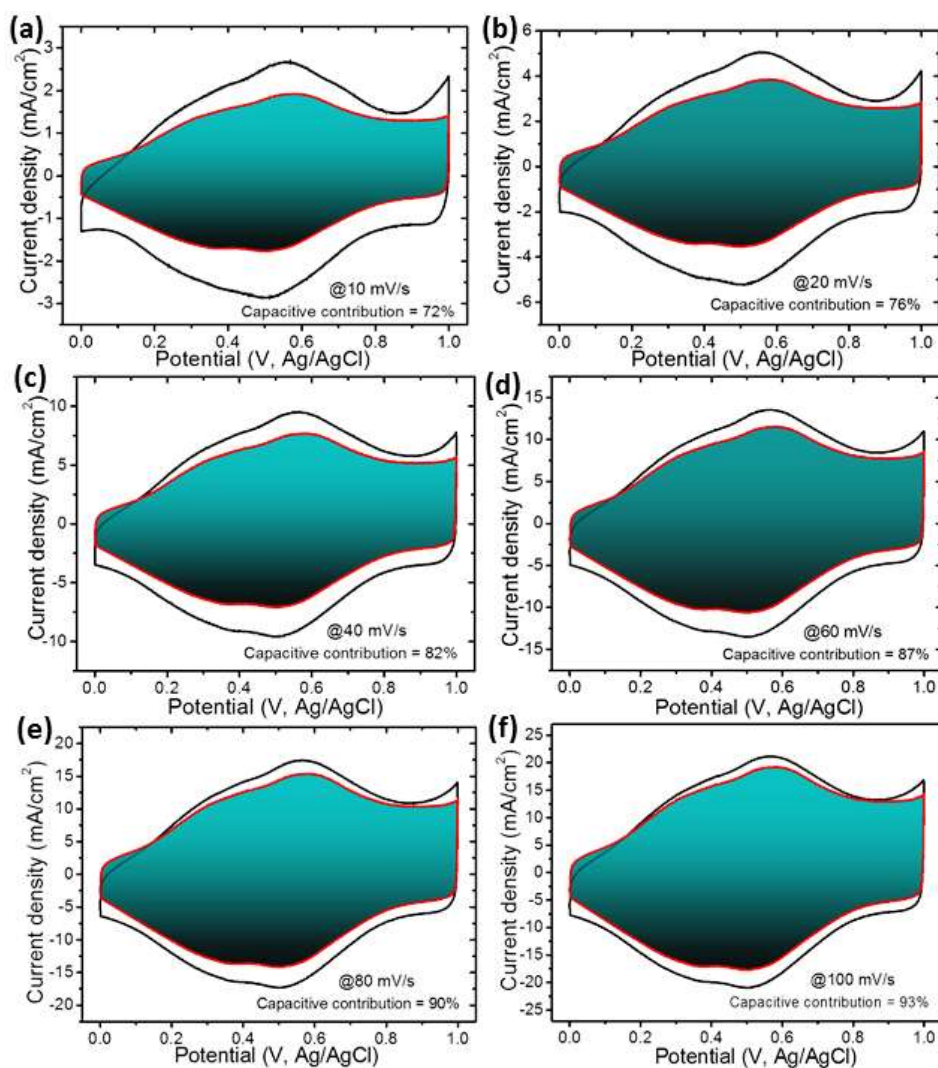


Figure S14 Electrochemical characterization of RuO₂@CF, Related to Figure 5. Cyclic voltammety curves for RuO₂@CF electrode at different scan rates from 10 to 100 mV/s. The capacitive contribution to the total current is shown by the shaded region.

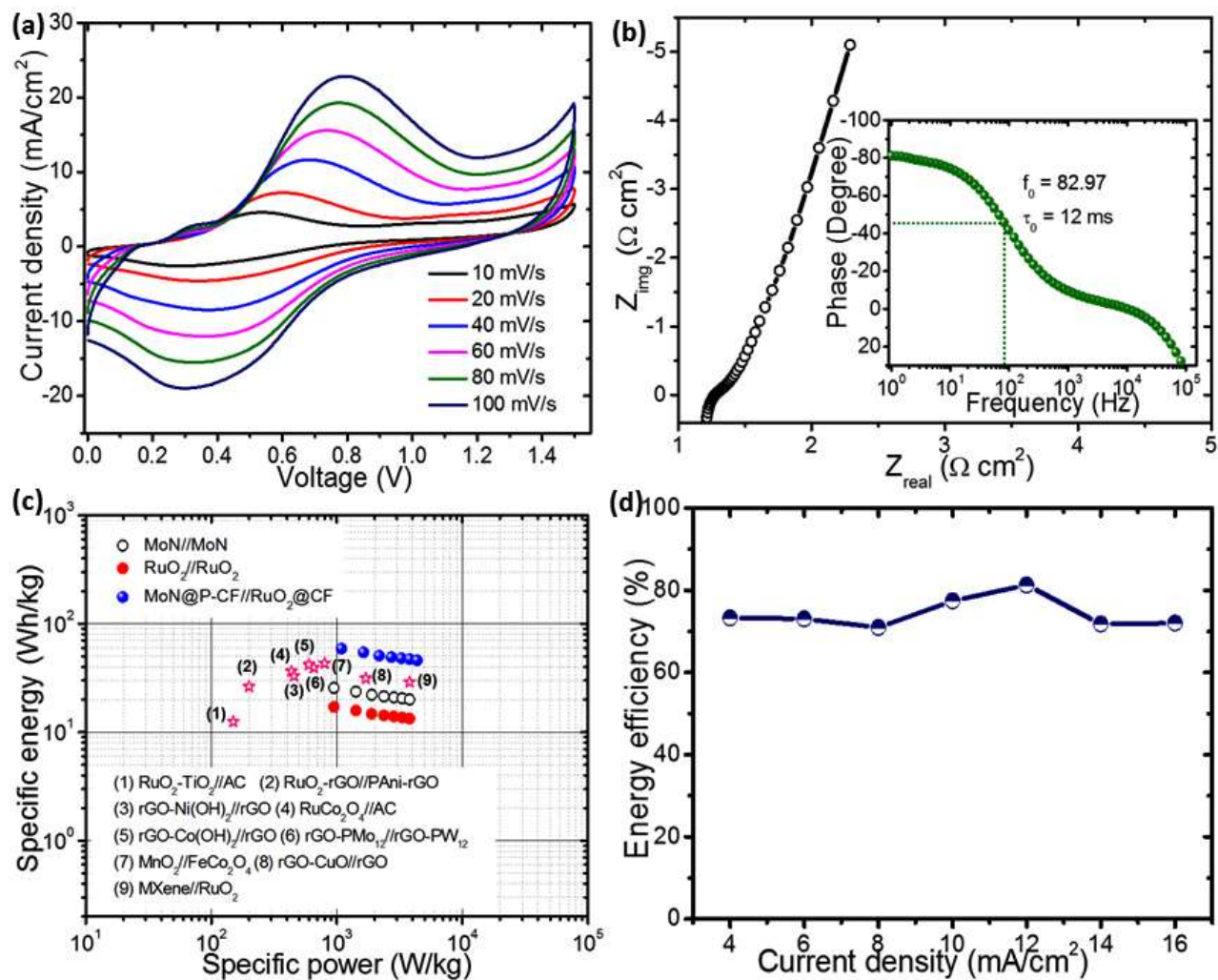


Figure 15 Electrochemical characterization of MoN@P-CF//RuO₂@CF cell, Related to Figure 6.

(a) CV profiles for MoN@P-CF//RuO₂@CF asymmetric cell recorded at different scan rates. (b) Nyquist plot with their corresponding bode plot, confirming ultra-fast characteristics of the cell. (c) Ragone plot showing comparison of specific energy and specific power values with RuO₂ based asymmetric systems. (d) Energy efficiency of device calculated at different current densities.

Table S1 Electrochemical performances of nitrides based electrodes for supercapacitor application, Related to Figure 3

| Material | Electrolyte | Capacitance | Ref. |
|--------------------------------|--------------------------------------|------------------------------------------------------------------------|-----------------------|
| MoN@P-CF | 1 M H ₂ SO ₄ | 400 mF/cm ² at 2 mA/cm ² | Present work |
| Molybdenum Oxynitride | 1 M KOH | 736.6 mF/cm ² at 10 mV/s | Ruan et al. 2017 |
| TiN | 0.5 M H ₂ SO ₄ | 27.3 mF/cm ² at a current density of 1.0 mA/cm ² | Wei et al. 2018 |
| CrN | 0.5 M H ₂ SO ₄ | 12.8 mF/cm ² at 1.0 mA/cm ² | Wei et al. 2017 |
| TiN | 0.5 M K ₂ SO ₄ | 8.8 mF/cm ² at 100 mV/s | Achour et al. 2015 |
| MoN | 1 M H ₂ SO ₄ | 928 F/cm ³ at 2 mV/s | Xiao et al. 2017 |
| MoN | 1 M KOH | 130 mC/cm ² at 2 mA/cm ² | Nandi et al. 2018 |
| TiN | 1 M H ₂ SO ₄ | 10.9 mF/cm ² at 0.1 V/s | Zheng et al. 2018 |
| MoN _x /TiN | 1 M LiOH | 121.50 mF/cm ² for at 0.3 mA/cm ² | Xie et al. 2017 |
| Mo ₂ N | 1 M H ₂ SO ₄ | 172 F/g at 1 mV/s | Xue-liang et al. 2009 |
| Mo _x N | 4.4 M H ₂ SO ₄ | 315 F/cm ³ at 10 mV/s | Roberson et al. 1999 |
| Mo ₂ N | 1 M H ₂ SO ₄ | 171 F/g at 0.5 mA/cm ² | Zhang et al. 2016 |
| Mo ₃ N ₂ | 1 M KOH | 220 F/g at 50 mV/s | Lee et al. 2013 |
| Mo ₂ N | 0.5 Li ₂ SO ₄ | 722 F/cm ³ at 5 mV/s | Chen et al. 2017 |
| Mo ₂ N | 0.5 M K ₂ SO ₄ | 275 F/g | Shah et al. 2014 |
| Mo ₂ N@C-rGO | 1 M H ₂ SO ₄ | 514.54 F/g at 0.25 A/g | Sridhar et al. 2018 |
| TiN@MoS ₂ | 0.5 M H ₂ SO ₄ | 662.2 mF/cm ² at 1 mA/cm ² | Yu et al. 2017 |

Table S2 H₃O⁺ adsorption energies are reported referenced to the adsorption energy of CF pristine sheet. All energies are reported in electron volt (eV), Related to Figure 4.

| Model | ΔE_{ads} |
|--------------|-------------------------------------------|
| CF | 0.0 |
| P-CF | -1.02 |
| 2P1-CF | -1.30 |
| 2P2-CF | -1.25 |
| 2P31-CF | -1.23 |
| 2P32-CF | -1.44 |
| 2P4-CF | -0.57 |
| 2P5-CF | -0.63 |
| MoN | -5.77 |
| MoN@CF | -8.20 |
| MoN@CF-P | -8.47 |

Table S3 Atomic charges are reported for H3O+ adsorption site in the three molecular models shown in Figure S7, Related to Figure 4

| Atom | CF | P-CF I | P-CF II |
|------|---------|---------|---------|
| C1 | -0.028 | -0.313 | -0.414 |
| C2 | 0.009 | -0.073 | 0.002 |
| C3 | -0.082 | 0.171 | 0.062 |
| C4 | 0.226 | -0.114 | -0.025 |
| C5 | 0.172 | -0.335 | -0.439 |
| C6 | -0.150 | -0.107 | 0.126 |
| C7 | -0.217 | 0.116 | -0.057 |
| C8 | 0.087 | -0.013 | 0.139 |
| C9 | 0.035 | 0.081 | -0.044 |
| C10 | 0.047 | 0.077 | -0.142 |
| C11 | 0.110 | 0.104 | 0.024 |
| C12 | 0.194 | -0.017 | 0.190 |
| C13 | -0.025 | -0.294 | -0.378 |
| C14 | -0.164 | 0.023 | -0.091 |
| C15 | -0.270 | -0.124 | 0.087 |
| C0 | 0.0272 | NA | NA |
| P | NA | 1.125 | 1.121 |
| O | -1.0396 | -0.9587 | -1.0241 |
| H1 | 0.5356 | 0.5014 | 0.5365 |
| H2 | 0.5562 | 0.5178 | 0.5320 |
| H3 | 0.0589 | -0.1945 | 0.0465 |

Table S4 Atomic charges are reported for complexes of H₃O⁺ adsorbed on P-CF systems as depicted in Figure S9, Related to Figure 4 (Provided in Separate Excel sheet)

H₃O⁺ adsorption on P-doped CF at 2%.

Results shown in S9, 10 and Table S4 can be explained based on the atomic charges reported in table S4 (excel sheet). The adsorption of H₃O⁺ on 2P-CF fibers can be classified into two groups; the first group that display negative charges on the adsorbed proton as well as on adsorption site atoms (2P1-CF, 2P2-CF, and 2P4-CF) and the binding site is on P atoms. The second group has positive charge on the adsorbed proton and negative on the surrounding atoms (2P31-CF, 2P32-CF and 2P5-CF). The adsorption site of the latter group is on C atoms. In the first group, the repulsion between the adsorbed protons and the surrounding atoms decreases their stabilities, while the attractive forces induced by the positive charges on P atoms and the adsorbed proton balanced them. Their affinity is dependent on the distance between the two phosphorus atoms. In the second group, the situation is reversed, the attractive electrostatic forces between the adsorbed protons and the binding site atoms increased their stabilities while the repulsive forces with the positive charges on P atoms decrease them. The affinity of this group is also dependent on the distance between the binding site and the two P atoms.

Table S5 AIM atomic charges are reported for the complexes of H₃O⁺ adsorbed on MoN, MoN@CF, and MoN@P-CF depicted in Figure S8. Related to Figure 4 (Provided in Separate Excel sheet)

Table S6 Comparison of electrochemical performances of MoN@P-CF//RuO₂@CF asymmetric supercapacitor cell, Related to Figure 6

| Material used | Type of cell | Capacitance | Maximum Energy density | Maximum Power density | Stability | Ref. |
|-------------------------------------------------------------------------|-----------------|------------------------------------------------------------------------|----------------------------------------------------|------------------------------------------------|--------------------------|---------------------|
| MoN@P-CF//RuO ₂ @CF | Asymmetric cell | 7.74 F/cm ³ at 4 mA/cm ² | 2.4 mWh/cm ³ | 174 mW/cm ³ | 89 % over 15000 cycles | Present work |
| VO _x //VN | Asymmetric cell | 1.01 F/cm ³ (44.9 F/g) at 0.5 mA/cm ² | 0.61 mWh/cm ³ at 0.5 mA/cm ² | 0.85 W/cm ³ at 5 mA/cm ² | 87.5 % over 10000 cycles | Lu et al. 2013 |
| TiN@GNS//Fe ₂ N@GNS | Asymmetric cell | 60 F/g at 4 A/g | 0.51 mWh/cm ³ at 2 A/g | 422.7 mW/cm ³ at 16 A/g | 99.8% over 20000 cycles | Zhu et al. 2015 |
| TiN/TiN | Symmetric cell | 0.33 F/cm ³ at 2.5 mA/cm ³ | 0.05 mWh/cm ³ at 2.5 mA/cm ³ | - | 82 % over 15000 cycles | Lu et al. 2012 |
| Mo ₂ N@rGO/Mo ₂ N@rGO | Symmetric cell | 15.4 F/cm ³ at 0.1 A/cm ³ | 1.05 mWh/cm ³ at 0.1 A/cm ³ | 3.15 W/cm ³ at 2 A/cm ³ | 85.7% over 4000 cycles | Ma et al. 2015 |
| PANI//C/Mo _x N | asymmetric cell | 65.2 F/g at 0.5 A/g | 14.1 Wh/kg at 0.5 A/g | - | 40.8 % over 3000 cycles | Tan et al. 2018 |
| MnO ₂ /GNS//MoS ₂ /GNS | asymmetric cell | 142 F/g (415 mF/cm ² and 19.3 F/cm ³) at 2 mV/s | 230.8 mWh/cm ² at | 5.0 kW/kg | 90 % over 5000 cycles | Yang et al. 2016 |
| NiS/MoS ₂ //AC | asymmetric cell | 108 F/g at 0.5 A/g | 40 Wh/kg at 0.5 A/g | 16.8 W/kg at 20 A/g | 100 % over 10000 cycles | Yang et al. 2017b |
| MoS ₂ -NiO//MoS ₂ -Fe ₂ O ₃ | Asymmetric cell | - | 39.6 Wh/kg at 1 A/g | - | 95 % over 6000 cycles | Wang et al. 2017 |
| RuO ₂ //Fe ₂ O ₃ | Asymmetric cell | 54.5 mF/cm ² at 0.13 mA/cm ² | 1.5 mWh/cm ³ at 0.13 mA/cm ² | - | 97 % over 5000 cycles | Wang et al. 2018 |

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